NSN 5961-00-926-7397



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-926-7397 **Inclosure Material:** Metal **Overall Length:** 0.520 inches **Overall Diameter:** 1.250 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: -100.0 collector to base voltage, dc and -80.0 collector to base voltage/static/emitter open and -80.0 collector to emitter voltage, dc with base short-circuited to emitter and -60.0 emitter to base voltage, instantaneous **Power Rating Per Characteristic:** 70.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug **Specification Data:**

Demilitarization:

Unit Of Measure:

Shelf Life:

N/a

81349-mil-s-19500/76 government specification

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